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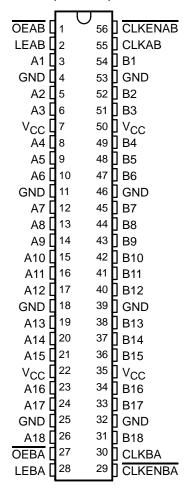
- **Members of the Texas Instruments** Widebus™ Family
- State-of-the-Art *EPIC-IIB™* BiCMOS Design Significantly Reduces Power Dissipation
- **UBT**™ (Universal Bus Transceiver) **Combines D-Type Latches and D-Type** Flip-Flops for Operation in Transparent, Latched, Clocked, or Clock-Enabled Mode
- Latch-Up Performance Exceeds 500 mA Per **JEDEC Standard JESD-17**
- Typical V_{OLP} (Output Ground Bounce) $< 0.8 \text{ V at V}_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$
- Flow-Through Architecture Optimizes PCB Layout
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

description

These 18-bit universal bus transceivers combine D-type latches and D-type flip-flops to allow data flow in transparent, latched, clocked, and clock-enabled modes.

Data flow in each direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. The clock can be controlled by the clock-enable (CLKENAB and CLKENBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is high. When LEAB is low, the A data is latched if CLKAB is held at a high or low logic level. If LEAB is low, the A data is stored in the latch/flip-flop on the low-to-high transition of CLKAB. Output enable OEAB is active low. When OEAB is low, the outputs are active. When OEAB is high, the outputs are in the high-impedance state.

SN54ABT16601 . . . WD PACKAGE SN74ABT16601...DGG OR DL PACKAGE (TOP VIEW)



Data flow for B to A is similar to that of A to B, but uses OEBA, LEBA, CLKBA, and CLKENBA.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT16601 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ABT16601 is characterized for operation from -40°C to 85°C.



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SN54ABT16601, SN74ABT16601 18-BIT UNIVERSAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS SCBS210C – JUNE 1992 – REVISED JANUARY 1997

FUNCTION TABLE†

	INPUTS						
CLKENAB	OEAB	LEAB	CLKAB	Α	В		
Х	Н	Х	Х	Χ	Z		
Х	L	Н	Χ	L	L		
Х	L	Н	Χ	Н	Н		
Н	L	L	Χ	Χ	в ₀ ‡ в ₀ ‡		
Н	L	L	Χ	Χ	в ₀ ‡		
L	L	L	\uparrow	L	L		
L	L	L	\uparrow	Н	Н		
L	L	L	L	Χ	в ₀ ‡		
L	L	L	Н	Χ	в ₀ ‡ в ₀ §		

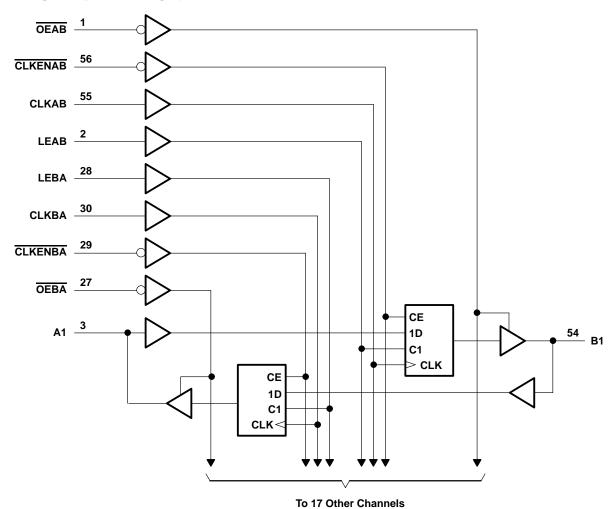
[†] A-to-B data flow is shown: B-to-A flow is similar but uses OEBA, LEBA, CLKBA, and CLKENBA.



[‡] Output level before the indicated steady-state input conditions were established

[§] Output level before the indicated steady-state input conditions were established, provided that CLKAB was low before LEAB went low

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (except I/O ports) (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high or power-off state, VO	–0.5 V to 5.5 V
Current into any output in the low state, IO: SN54ABT16601	96 mA
SN74ABT16601	
Input clamp current, I _{IK} (V _I < 0)	–18 mA
Output clamp current, I _{OK} (V _O < 0)	
Package thermal impedance, θ _{JA} (see Note 2): DGG package	
DL package	74°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51.



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recommended operating conditions (see Note 3)

					SN74AB1	UNIT	
			MIN	MAX	MIN	MAX	UNII
Vсс	Supply voltage		4.5	5.5	4.5	5.5	V
VIH	V _{IH} High-level input voltage		2		2		V
VIL	IL Low-level input voltage			0.8		0.8	V
٧ _I	V _I Input voltage		0	Vcc	0	Vcc	V
ЮН	High-level output current			-24		-32	mA
lOL	IOL Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
T _A	Operating free-air temperature	ir temperature		125	-40	85	°C

NOTE 3: Unused pins (input or I/O) must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DA	DAMETER	TEST COL	UDITIONS	Т	A = 25°C	;	SN54AB	Г16601	SN74AB1	Г16601	UNIT
PAI	RAMETER	TEST COI	NULLIONS	MIN	TYP [†]	MAX	MIN	MAX	MIN	MAX	UNII
VIK		$V_{CC} = 4.5 \text{ V},$	I _I = -18 mA			-1.2		-1.2		-1.2	V
	$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -3 \text{ mA}$	2.5			2.5		2.5			
\ _{\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\}		V _{CC} = 5 V,	$I_{OH} = -3 \text{ mA}$	3			3		3		V
VOH		V00 = 4.5.V	$I_{OH} = -24 \text{ mA}$	2			2				V
		VCC = 4.5 V	$I_{OH} = -32 \text{ mA}$	2*					2		
Voi		V _{CC} = 4.5 V, V _{CC} = 4.5 V,	$I_{OL} = 48 \text{ mA}$			0.55		0.55			V
VOL			I _{OL} = 64 mA			0.55*				0.55	V
V _{hys}					100						mV
	Control inputs	V _{CC} = 5.5 V,	Vi – Voe er CND			±1		±1		±1	
l _l	A or B ports		$V_I = V_{CC}$ or GND			±20**		±100		±20	μΑ
l _{off}		$V_{CC} = 0$,	V_I or $V_O \le 4.5 \text{ V}$			±100				±100	μΑ
ICEX		V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50		50		50	μΑ
lo [‡]		V _{CC} = 5.5 V,	V _O = 2.5 V	-50	-100	-180	– 50	-180	-50	-180	mA
IOZH§		V _{CC} = 5.5 V,	V _O = 2.7 V			10		10		10	μΑ
lozL§		$V_{CC} = 5.5 \text{ V},$	V _O = 0.5 V			-10		-10		-10	μΑ
		Vcc = 5.5 V.	Outputs high		1.9	3		2		3	
Icc	A or B ports	$I_{O} = 0$,	Outputs low		28	36		35		36	mA
	$V_I = V_{CC}$ or GND	$V_I = V_{CC}$ or GND	Outputs disabled		1.6	3		2		3	
A1 ¶						50				50	μΑ
∆ICC¶		Other inputs at VC	C or GND					1.5			mA
Ci	Control inputs	$V_{ } = 2.5 \text{ V or } 0.5 \text{ V}$			3						pF
C _{io}	A or B ports	$V_0 = 2.5 \text{ V or } 0.5 \text{ V}$	/		9						pF

^{*} On products compliant to MIL-PRF-38535, this parameter does not apply.



^{**} This limit applies only to the SN74ABT16601.

[†] All typical values are at $V_{CC} = 5 \text{ V}$.

[‡] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

[§] The parameters I_{OZH} and I_{OZL} include the input leakage current.

 $[\]P$ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

				SN54ABT16601		SN74AB1	UNIT	
				MIN	MAX	MIN	MAX	UNIT
f _{clock} Clock frequency			0	150	0	150	MHz	
I Bulan dimedian	Pulse duration	LEAB or LEBA high	LEAB or LEBA high			2.5		ns
۱W	t _W Pulse duration	CLKAB or CLKBA high or low	3		3		115	
		A before CLKAB↑ or B before CLKBA↑		4.6		4		
١.	Catua tima	A before LEAB↓ or B before LEBA↓ CLK high	CLK high	2.5		2.5		ns
t _{su}	Setup time		1.3		1		115	
		CLKEN before CLK↑		2.9		2.5		
		A after CLKAB↑ or B after CLKBA↑		0.4		0		
t _h Hold time	Hold time	A after LEAB↓ or B after LEBA↓		2.8		2		ns
		CLKEN after CLK↑		0		0		

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

				SN5	4ABT16	601		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
f _{max}			150	200		150		MHz
t _{PLH}	A or B	B or A	1.5	2.5	4.1	1	4.6	ns
^t PHL		BULK	1.5	3.4	4.7	1	5.1	113
tPLH	LEAB or LEBA	B or A	2	3.4	4.7	1	5.6	ns
t _{PHL}	LLAD OF LLDA	DOLY	2	3.7	5	1	5.5	113
tpLH	CLKAB or CLKBA	B or A	1.5	3.2	4.5	1	5.2	ns
t _{PHL}	CLNAD OF CLNDA	BULK	1.5	3.2	4.4	1	5	115
^t PZH	<u> </u>	B or A	2	4	5	1	5.7	ns
t _{PZL}	OEAB or OEBA	BULK	2	4.2	5.6	1	6	115
^t PHZ	OFAR as OFRA	B or A	2	4.5	5.8	1	6.8	ne
t _{PLZ}	OEAB or OEBA	BULK	1.5	3.4	5.3	1	6.3	ns

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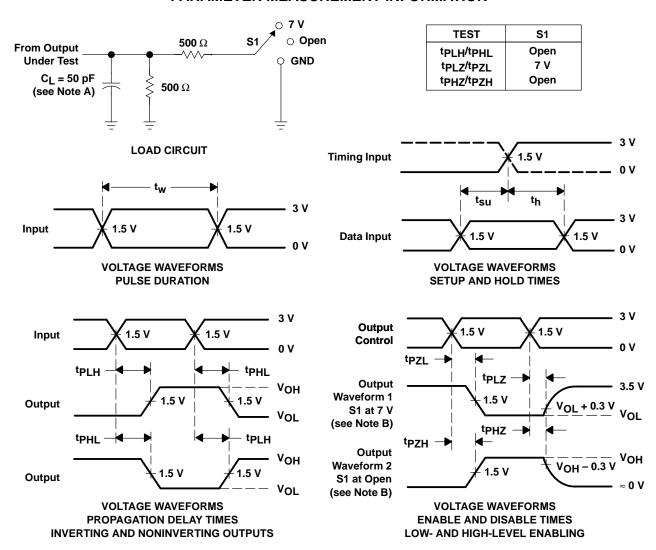
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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

				SN7	4ABT16	601		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
fmax			150	200		150		MHz
^t PLH	A or B	B or A	1.5	2.5	3.6	1.5	4	ns
^t PHL		D UI A	1.5	3.4	4.7	1.5	4.9	115
^t PLH	LEAB or LEBA	B or A	2	3.4	4.7	2	5	ns
t _{PHL}	LEAD OF LEDA	D OI A	2	3.7	5	2	5.2	115
^t PLH	CLKAB or CLKBA	B or A	1.5	3.2	4.5	1.5	4.7	no
t _{PHL}	CLKAB of CLKBA	D OI A	1.5	3.2	4.4	1.5	4.6	ns
^t PZH		B or A	2	4	5	2	5.5	no
^t PZL	OEAB or OEBA	D UI A	2	4.2	5.6	2	5.8	ns
^t PHZ	OFAR as OFRA	B or A	2	4.5	5.4	2	6.2	nc
^t PLZ	OEAB or OEBA	BULA	1.5	3.4	4.7	1.5	5.4	ns



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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